DESCRIPTION

The SPN1074 is the N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

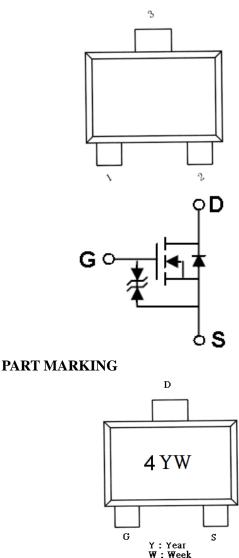
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

- N-Channel 30V/0.95A,RDs(ON)=550mΩ@VGs=4.5V 30V/0.75A,RDs(ON)=650mΩ@VGs=2.5V 30V/0.65A,RDs(ON)=850mΩ@VGs=1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- SOT-723 package design

PIN CONFIGURATION(SOT-723)





PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1074S72RGB	SOT-723	4

* SPN1074S72RGB : Tape Reel ; Pb – Free ; Halogen – Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit
Drain-Source Voltage		VDSS	30	V
Gate –Source Voltage		VGSS	±12	V
Continuous Drain Current(TJ=150°C)	Ta=25°C	ID	0.65	Α
Pulsed Drain Current (*)		Idm	0.95	Α
Thermal Resistance-Junction to Ambient		Røja	375	°C/W
Power Dissipation	Ta=25°C	Pd	0.15	W
Operating Junction Temperature		TJ	-55/150	°C
Storage Temperature Range		Tstg	-55/150	°C

(*) Pulse width limited by safe operating area

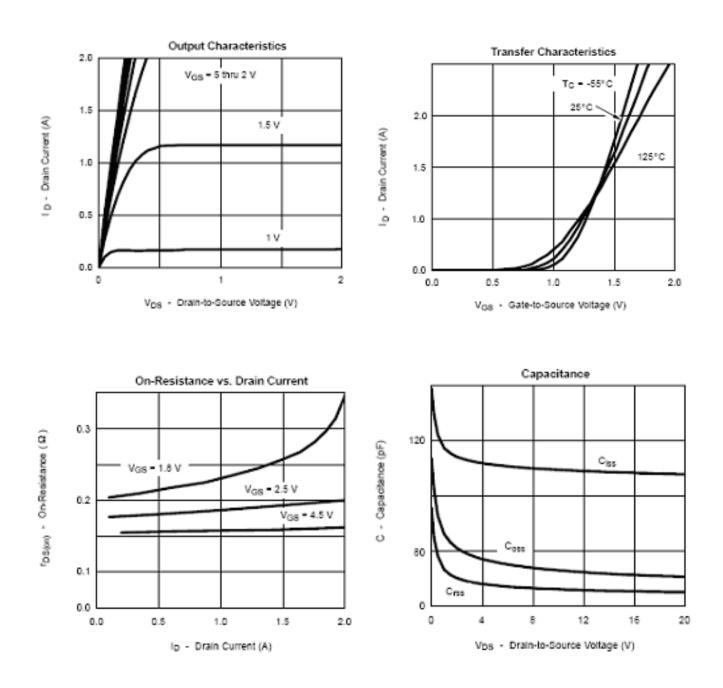


ELECTRICAL CHARACTERISTICS

(TA=25°C Unless otherwise noted)

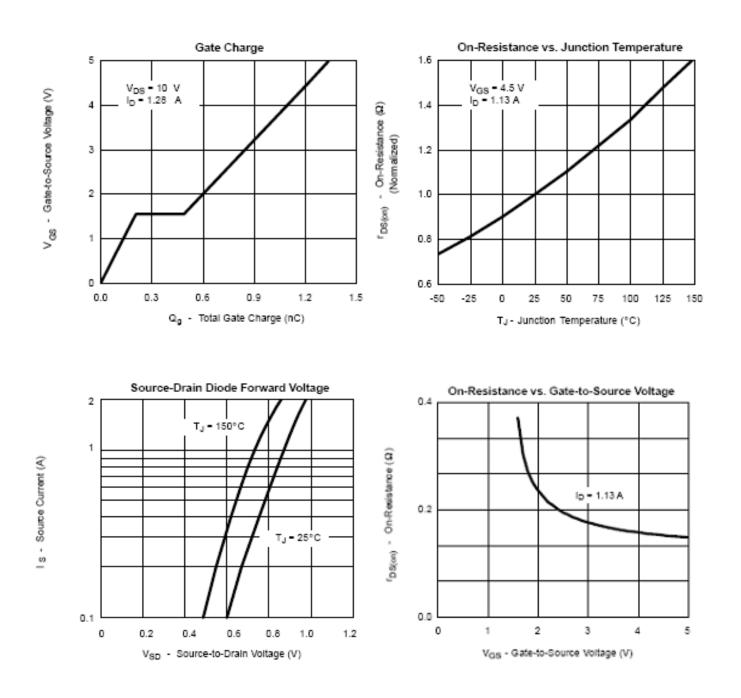
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	·					<u>.</u>	
Drain-Source Breakdown Voltage	V(BR)DSS VGS=0V,ID= 250uA		30			X.Z	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.35		1.0	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±30	uA	
		$V_{DS}=48V, V_{GS}=0V$ $T_{J}=25^{\circ}C$			30		
Zero Gate Voltage Drain Current	Idss	$V_{DS}=48V, V_{GS}=0V$ $T_{J}=55^{\circ}C$			100	- uA	
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 5V$	0.7			A	
Drain-Source On-Resistance	RDS(on)	Vgs=4.5V,Id=0.95A		0.45	0.55	Ω	
		VGS=2.5V,ID=0.75A		0.50	0.65		
	C	VGS=1.8V,ID=0.65A		0.70	0.85	0	
Forward Transconductance	gfs	VDS=10V,ID=0.4A		1.0		S	
Diode Forward Voltage	Vsd	Is=0.15A,VGs=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg	Vds=10V,Vgs=4.5V,		1.2	1.5	nC	
Gate-Source Charge	Qgs	ID=0.6A		0.2			
Gate-Drain Charge	Qgd			0.3			
Input Capacitance	Ciss			7.2		pF	
Output Capacitance	Coss	$V_{DS} = 10V, f = 1 MHz,$ $V_{GS} = 0V$		17			
Reverse Transfer Capacitance	Crss	V GS = U V		1.6			
	td(on)	U 10UD 100		5	10		
Turn-On Time	tr	$V_{DD}=10V,RL=10\Omega$, ID=0.5A		8	15	ns	
	td(off)	VGEN=4.5V ,RG=6 Ω		10	18		
Turn-Off Time	tf]		1.2	2.8		

TYPICAL CHARACTERISTICS



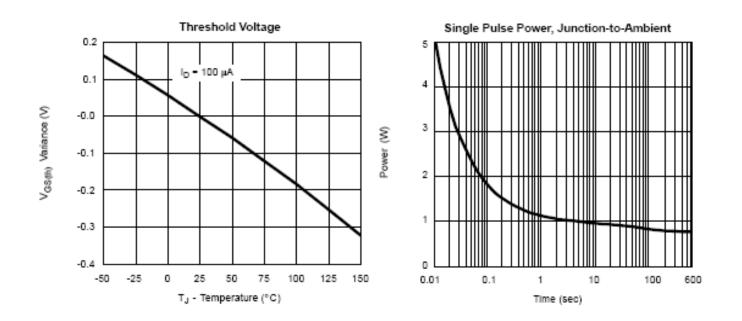
2015/6/18 Ver.1

TYPICAL CHARACTERISTICS

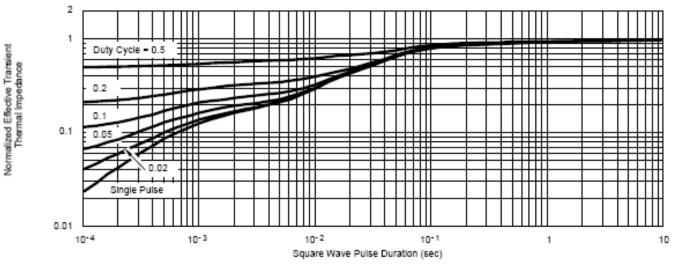


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TYPICAL CHARACTERISTICS

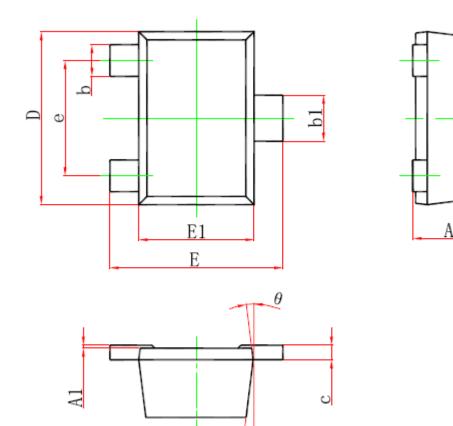


Normalized Thermal Transient Impedance, Junction-to-Foot



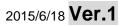
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SOT-723 PACKAGE OUTLINE



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α		0.500		0.020	
A1	0.000	0.050	0.000	0.002	
b	0.170	0.270	0.007	0.011	
b1	0.270	0.370	0.011	0.015	
С		0.150		0.006	
D	1.150	1.250	0.045	0.049	
E	1.150	1.250	0.045	0.049	
E1	0.750	0.850	0.030	0.033	
е	0.800TYP.		0.031TYP.		
θ	7°	REF.	7° REF.		

θ





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